

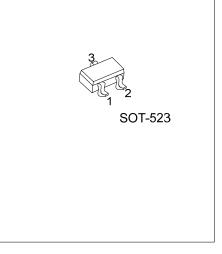
BAT54TB SCHOTTKY BARRIER DIODES

DESCRIPTION

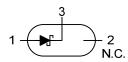
Planar Schottky barrier diodes are encapsulated in the SOT-523 small plastic SMD package. Single diodes and dual diodes with different pin configuration are available.

FEATURES

- * Low forward voltage
- * Guard ring protected
- * Small plastic SMD package



SYMBOL



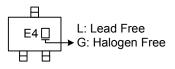
ORDERING INFORMATION

Ordering Number		Deekeere	Pin Assignment			Decking
Lead Free	Halogen Free	Package	1	2	3	Packing
BAT54TBL-AN3-R	BAT54TBG-AN3-R	SOT-523	Α	NC	К	Tape Reel

Note: Pin Assignment: A: Anode K: Cathode

ВАТ54ТВ <u>Ģ-АŅ3</u> -Ŗ	
(1)Packing Ty	vpe (1) R: Tape Reel
(2)Package T	ype (2) AN3: SOT-523
(3)Green Pacl	kage (3) G: Halogen Free and Lead Free, L: Lead Free

MARKING



■ ABSOLUTE MAXIMUM RATINGS

PARAMETER	SYMBOL	RATINGS	UNIT			
PER DIODE						
Continuous Reverse Voltage	V _R	30	V			
Continuous Forward Current	I _F	200	mA			
Repetitive Peak Forward Current (t _P <1s, δ≤0.5)	I _{FRM}	300	mA			
Non-repetitive Peak Forward Current (t _P <10ms)	I _{FSM}	600	mA			
Junction Temperature	TJ	+125	°C			
Storage Temperature	T _{STG}	-60 ~ +150	°C			
PER DEVICE						
Power Dissipation (T _A ≤25°C)	PD	230	mW			

Note: Absolute maximum ratings are those values beyond which the device could be permanently damaged. Absolute maximum ratings are stress ratings only and functional device operation is not implied.

THERMAL DATA

PARAMETER	SYMBOL	RATINGS	UNIT	
Junction to Ambient	θ _{JA}	500	°C/W	

■ ELECTRICAL CHARACTERISTICS (T_A = 25°C, unless otherwise specified.)

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Forward Voltage (See Fig.1)	VF	I _F = 0.1mA			240	mV
		I _F = 1mA			320	mV
		I _F = 10mA			400	mV
		I _F = 30mA			500	mV
		I _F = 100mA			800	mV
Reverse Current (See Fig.2)	I _R	V _R = 25V			2	μA
Reverse Recovery Time (see Fig.4)	t _{rr}	When switched from I _F =10mA to I _R = 10mA, R _L = 100 Ω measured at I _R = 1mA			5	ns
Diode Capacitance (see Fig.3)	CD	f = 1 MHz, V _R = 1V;			10	pF



BAT54TB

DIODE

TYPICAL CHARACTERISTICS

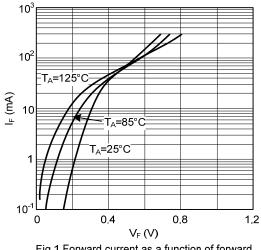


Fig.1 Forward current as a function of forward voltage; typical values.

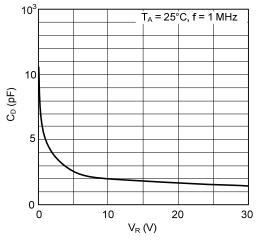
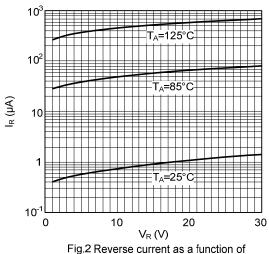


Fig.3 Diode capacitance as a function of reverse voltage; typical values.



reverse voltage; typical values

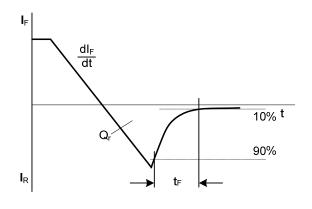


Fig.4 Reverse recovery definitions

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